Vishay Semiconductors

Hyperfast Rectifier, 16 A FRED Pt[®]



O Cathode

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LINKS TO ADDITIONAL RESOURCES

Anode 2 C



PRIMARY CHARACTERISTICS						
I _{F(AV)} 16 A						
V _R	600 V					
V _F at I _F (T _J = 150 °C)	1.24 V					
t _{rr}	30 ns					
T _J max.	175 °C					
Package	SMPD (TO-263AC)					
Circuit configuration	Single					

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current



COMPLIANT

HALOGEN

FREE

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)} ⁽¹⁾	T _C = 127 °C	16	٨		
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \text{ °C}, 10 \text{ ms sine pulse}$ 160		А		

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-		
Ferrural values	V _F	I _F = 16 A	-	1.65	2.15	V	
Forward voltage		I _F = 16 A, T _J = 150 °C	-	1.24	1.65		
Deverae leekeese evirrent	I _R	$V_{R} = V_{R}$ rated	-	-	20		
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA	
Junction capacitance	CT	V _R = 600 V	-	16	-	pF	

Note

⁽¹⁾ Mounted on infinite heatsink

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DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50$	A/μs, V _R = 30 V	-	30	-	
Reverse recovery time	+	I _F = 0.5 A, I _R = 1 A, I	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	30	
neverse recovery time	t _{rr}	T _J = 25 °C		-	43	-	A
		T _J = 125 °C		-	92	-	
Peak recovery current	I	T _J = 25 °C	I _F = 16 A, dI _F /dt = 500 A/μs, V _B = 400 V	-	7.7	-	
Feak recovery current	IRRM	T _J = 125 °C		-	13.8	-	~
Reverse recovery charge Q _{rr}	0	T _J = 25 °C]	-	150	-	μC
neverse recovery charge	Q _{rr}	T _J = 125 °C		-	600	-	μΟ

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C	
Thermal resistance, junction to mount	R _{thJM}		-	1.2	1.7	°C/W	
Approximate weight				0.55		g	
Marking device		Case style SMPD (TO-263AC)		16EI	DH06		

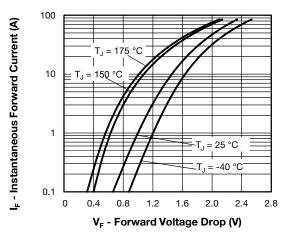


Fig. 1 - Typical Forward Voltage Drop Characteristics

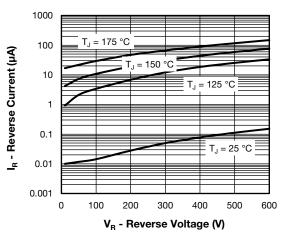
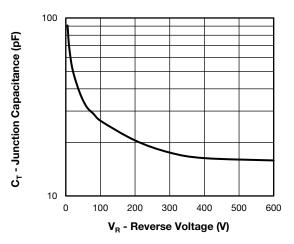
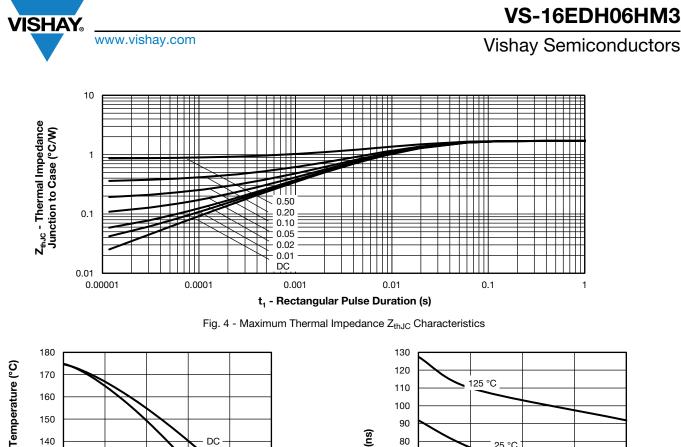


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage







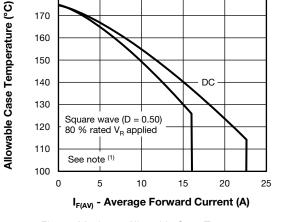


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

Note

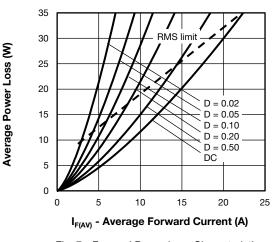


Fig. 7 - Forward Power Loss Characteristics

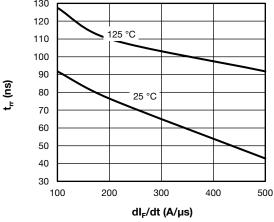


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

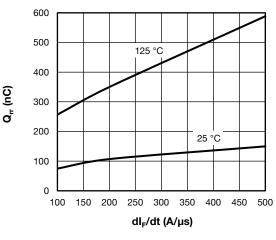


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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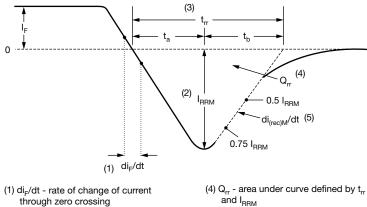
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VS-16EDH06HM3

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(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current. Fig. 9 - Reverse Recovery Waveform and Definitions

and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

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Device cod

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de	vs-	16	Е	D	н	06	н	М3	
	1	2	3	4	5	6	7	8	•
	1 ·		hay Sem			oduct			
	2 - 3 -		rent rati cuit cont	0.	,				
	4 -		E = single die D = SMPD package						
	5 -		Process type, H = hyperfast recovery						
	6 - 7 -	- Vol	Voltage code (06 = 600 V) H = AEC-Q101 qualified						

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
2000	2000	13" diameter plastic tape and reel					
	QUANTITY PER REEL	QUANTITY PER REEL MINIMUM ORDER QUANTITY					

Note

(1) AEC-Q101 qualified

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95604					
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				

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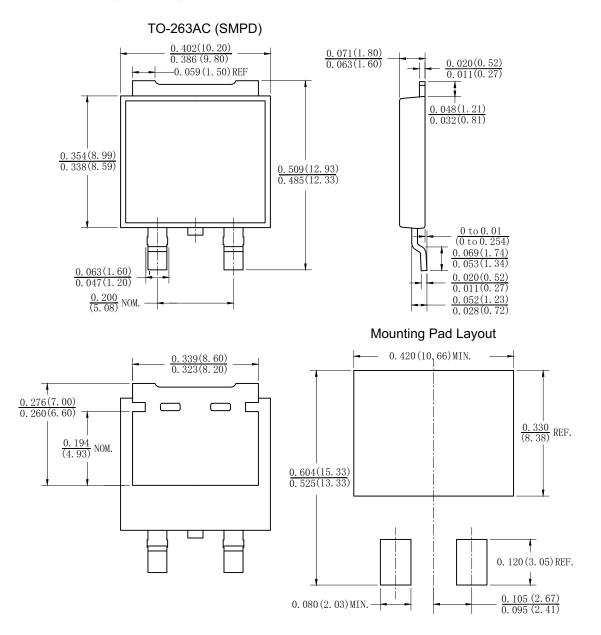
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TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





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